TOSHIBA Transistor Silicon NPN Epitaxial Type

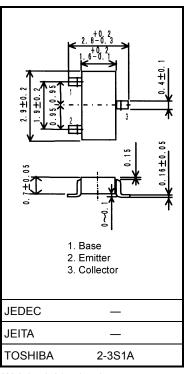
# 2SC5738

#### High-Speed Switching Applications DC-DC Converter Applications

- High DC current gain:  $h_{FE} = 400$  to 1000 (IC = 0.5 A)
- Low collector-emitter saturation voltage:  $V_{CE}$  (sat) = 0.15 V (max)
- High-speed switching:  $t_f = 90 \text{ ns}$  (typ.)

#### Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	40	V	
Collector-emitter voltage		V <sub>CEX</sub>	30	V	
Collector-emitter voltage		V <sub>CEO</sub>	20	V	
Emitter-base voltage		V <sub>EBO</sub>	7	V	
Collector current	DC	Ι <sub>C</sub>	3.5	А	
	Pulse	I <sub>CP</sub>	6.0	A	
Base current		Ι <sub>Β</sub>	350	mA	
Collector power dissipation	DC	P <sub>C</sub>	625	mW	
	t = 10 s	(Note)	1000		
Junction temperature		Тј	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	



Weight: 0.01 g (typ.)

Note: Mounted on an FR4 board (glass epoxy, 1.6 mm thick, Cu area: 645 mm<sup>2</sup>)

#### **Electrical Characteristics (Ta = 25°C)**

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	$V_{CB}=40~V,~I_{E}=0$	_		100	nA
Emitter cut-off current		I <sub>EBO</sub>	$V_{EB}=7~V,~I_C=0$	_	_	100	nA
Collector-emitter breakdown voltage		V (BR) CEO	$I_C = 10 \text{ mA}, I_B = 0$	20	_	_	V
DC current gain		h <sub>FE</sub> (1)	$V_{CE} = 2 V, I_C = 0.5 A$	400	_	1000	
		h <sub>FE</sub> (2)	$V_{CE} = 2 V, I_C = 1.6 A$	200			
Collector-emitter saturation voltage		V <sub>CE (sat)</sub>	$I_{C} = 1.6 \text{ A}, I_{B} = 32 \text{ mA}$			0.15	V
Base-emitter saturation voltage		V <sub>BE (sat)</sub>	$I_{C} = 1.6 \text{ A}, I_{B} = 32 \text{ mA}$	_	_	1.10	V
Collector output capacitance		C <sub>ob</sub>	$V_{CB} = 10 \text{ V}, \text{ I}_{E} = 0, \text{ f} = 1 \text{ MHz}$	_	18	_	pF
Switching time	Rise time	t <sub>r</sub>	See Figure 1.		100		
	Storage time	t <sub>stg</sub>	$V_{CC}\simeq$ 12 V, $R_L=7.5~\Omega$		350		ns
	Fall time	t <sub>f</sub>	$I_{B1} = -I_{B2} = 53 \text{ mA}$		90		

Unit: mm

### Marking

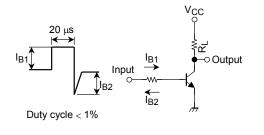
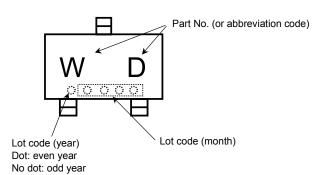
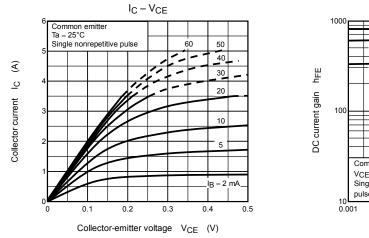
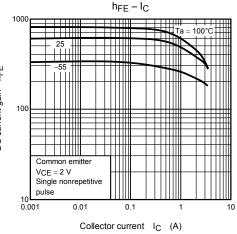


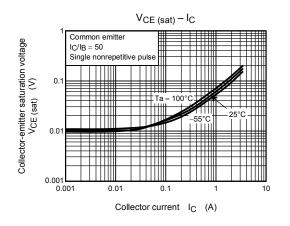
Figure 1 Switching Time Test Circuit & Timing Chart

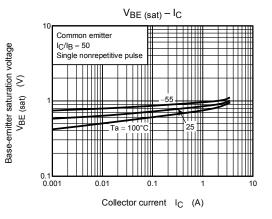


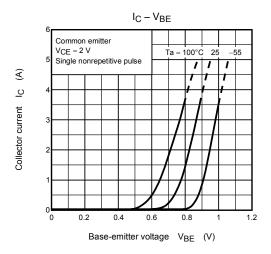
## TOSHIBA



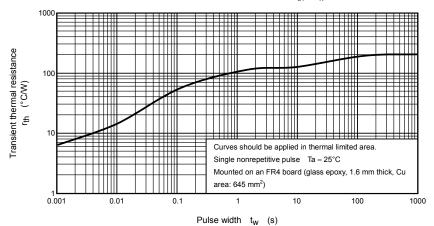








2004-07-01



#### Safe Operating Area 10 IC max (pulsed) • 0 μs♦ IC max (continuous) 100 μs♦ \_1 ms♦ 10 ms ♦ ₹ 100 ms + <u>ں</u> 10 s♦\* DC operation \* Collector current (Ta = 25°C) Single nonrepetitive pulse Ta = 25°C Note that the curves for 100 ms\*, 10 s\* and DC operation\* will be different when the devices aren't mounted on an FR4 board (glass epoxy, 1.6 mm thick, Cu area: 645 mm<sup>2</sup>). These characteristic curves must be derated linearly with increase in temperature. 0.1 max CEO 0.01 0.1 10 100 Collector-emitter voltage $~V_{CE}~~(V)$

Transient Thermal Resistance rth - tw

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